Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	Coldfire V1
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	CANbus, I²C, SCI, SPI, USB OTG
Peripherals	LVD, PWM, WDT
Number of I/O	51
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcf51jm64vlh

1 MCF51JM128 Family Configurations

1.1 Device Comparison

The MCF51JM128 series consists of the devices compared in Table 1.

Table 1. MCF51JM128 Series Device Comparison

Feature	MCF51JM128			MCF51JM64			MCF51JM32		
	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin
Flash memory size (KB)	128			64			32		
RAM size (KB)	16			16			16		
V1 ColdFire core with BDM (background debug module)	Yes								
ACMP (analog comparator)	Yes								
ADC channels (12-bit)	12		8	12		8	12		8
CAN (controller area network)	Yes	Yes	No	Yes	Yes	No	Yes	Yes	No
RNGA + CAU	Yes[1]								
CMT (carrier modulator timer)	Yes								
COP (computer operating properly)	Yes								
IIC1 (inter-integrated circuit)	Yes								
IIC2	Yes	No		Yes	No		Yes	No	
IRQ (interrupt request input)	Yes								
KBI (keyboard interrupts)	8	8	6	8	8	6	8	8	6
LVD (low-voltage detector)	Yes								
MCG (multipurpose clock generator)	Yes								
Port I/O[2]	66	51	33	66	51	33	66	51	33
RGPIO (rapid general-purpose I/O)	16	6	0	16	6	0	16	6	0
RTC (real-time counter)	Yes								
SCI1 (serial communications interface)	Yes								
SCI2	Yes								
SPI1 (serial peripheral interface)	Yes								
SPI2	Yes								
TPM1 (timer/pulse-width modulator) channels	6	6	4	6	6	4	6	6	4
TPM2 channels	2								
USBOTG (USB On-The-Go dual-role controller)	Yes								
XOSC (crystal oscillator)	Yes								

1 Only existed on special part number

2 Up to 16 pins on Ports A, H, and J are shared with the ColdFire Rapid GPIO module.

1.2 Block Diagram

Figure 1 shows the connections between the MCF51JM128 series pins and modules.

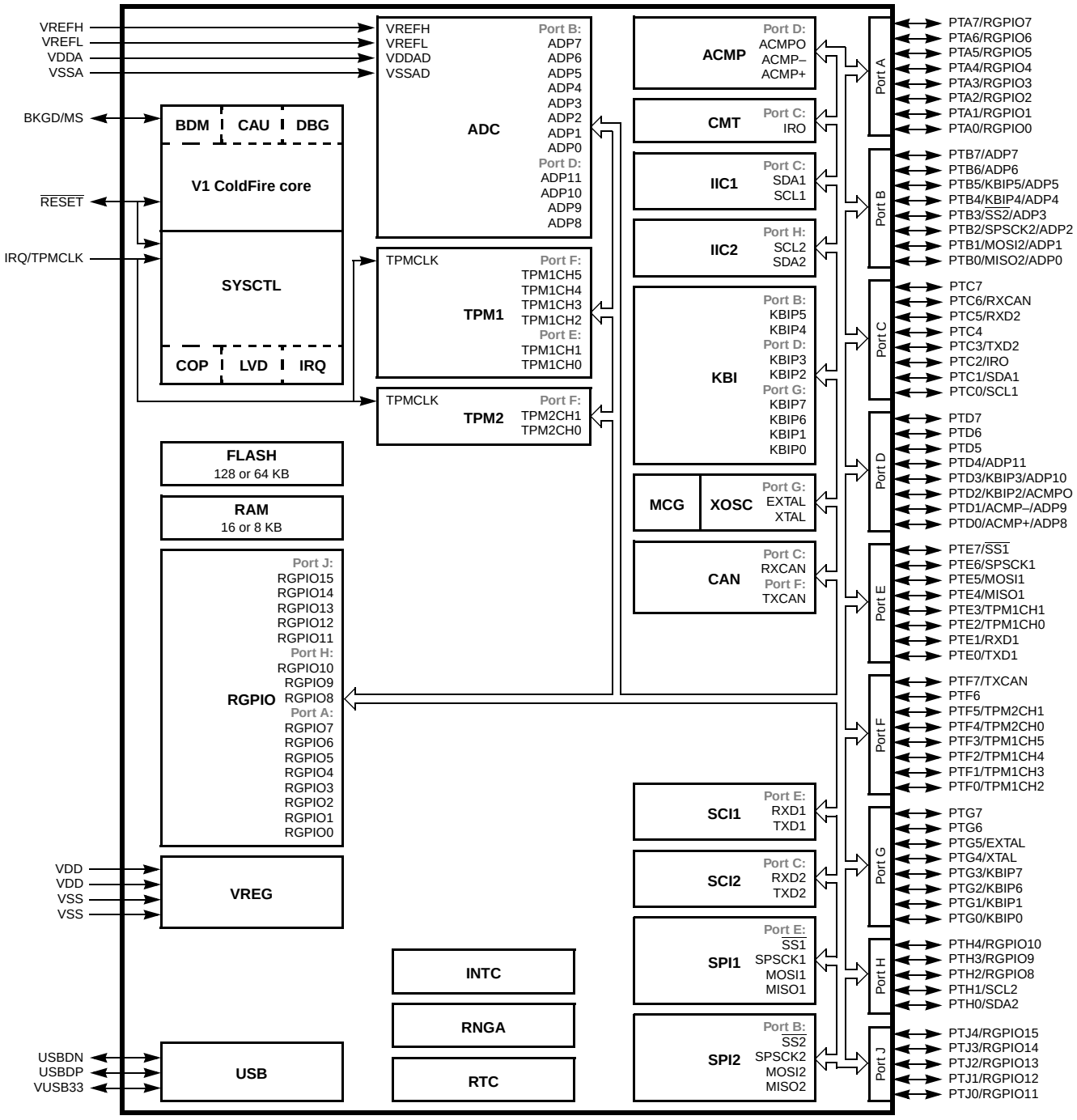


Figure 1. MCF51JM128 Block Diagram

- RTC
  - 8-bit modulus counter with binary- or decimal-based prescaler
  - External clock source for precise time base, time-of-day, calendar or task scheduling functions
  - Free running on-chip low power oscillator (1 kHz) for cyclic wake-up without external components
- Carrier modulator timer (CMT)
  - carrier generator, modulator, and transmitter drive the infrared out (IRO) pin
  - operation in independent high/low time control, baseband, FSK, and direct IRO control modes
- Input/Output
  - 66 GPIOs
  - Eight keyboard interrupt pins with selectable polarity
  - Hysteresis and configurable pull-up device on all input pins; configurable slew rate and drive strength on all output pins
  - 16 bits of Rapid GPIO connected to the processor's local 32-bit platform bus with set, clear, and faster toggle functionality

1.4 Part Numbers

Table 3. Orderable Part Number Summary

Freescale Part Number	Description	Flash / SRAM (KB)	Package	Temperature
MCF51JM128EVLK	MCF51JM128 ColdFire Microcontroller with CAU and RNGA Enabled	128 / 16	80 LQFP	–40 to +105 °C
MCF51JM128VLK	MCF51JM128 ColdFire Microcontroller	128 / 16	80 LQFP	–40 to +105 °C
MCF51JM128EVLH	MCF51JM128 ColdFire Microcontroller with CAU and RNGA Enabled	128 / 16	64 LQFP	–40 to +105 °C
MCF51JM128VLH	MCF51JM128 ColdFire Microcontroller	128 / 16	64 LQFP	–40 to +105 °C
MCF51JM128EVQH	MCF51JM128 ColdFire Microcontroller with CAU and RNGA Enabled	128 / 16	64 QFP	–40 to +105 °C
MCF51JM128VQH	MCF51JM128 ColdFire Microcontroller	128 / 16	64 QFP	–40 to +105 °C
MCF51JM128EVLD	MCF51JM128 ColdFire Microcontroller with CAU and RNGA Enabled	128 / 16	44 LQFP	–40 to +105 °C
MCF51JM128VLD	MCF51JM128 ColdFire Microcontroller	128 / 16	44 LQFP	–40 to +105 °C
MCF51JM64EVLK	MCF51JM64 ColdFire Microcontroller with CAU and RNGA Enabled	64 / 16	80 LQFP	–40 to +105 °C
MCF51JM64VLK	MCF51JM64 ColdFire Microcontroller	64 / 16	80 LQFP	–40 to +105 °C
MCF51JM64EVLH	MCF51JM64 ColdFire Microcontroller with CAU and RNGA Enabled	64 / 16	64 LQFP	–40 to +105 °C
MCF51JM64VLH	MCF51JM64 ColdFire Microcontroller	64 / 16	64 LQFP	–40 to +105 °C
MCF51JM64EVQH	MCF51JM64 ColdFire Microcontroller with CAU and RNGA Enabled	64 / 16	64 QFP	–40 to +105 °C
MCF51JM64VQH	MCF51JM64 ColdFire Microcontroller	64 / 16	64 QFP	–40 to +105 °C

Table 3. Orderable Part Number Summary (continued)

MCF51JM64EVLD	MCF51JM64 ColdFire Microcontroller with CAU and RNGA Enabled	64 / 16	44 LQFP	–40 to +105 °C
MCF51JM64VLD	MCF51JM64 ColdFire Microcontroller	64 / 16	44 LQFP	–40 to +105 °C
MCF51JM32EVLK	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	80 LQFP	–40 to +105 °C
MCF51JM32VLK	MCF51JM32 ColdFire Microcontroller	32 / 16	80 LQFP	–40 to +105 °C
MCF51JM32EVLH	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	64 LQFP	–40 to +105 °C
MCF51JM32VLH	MCF51JM32 ColdFire Microcontroller	32 / 16	64 LQFP	–40 to +105 °C
MCF51JM32EVQH	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	64 QFP	–40 to +105 °C
MCF51JM32VQH	MCF51JM32 ColdFire Microcontroller	32 / 16	64 QFP	–40 to +105 °C
MCF51JM32EVLD	MCF51JM32 ColdFire Microcontroller with CAU and RNGA Enabled	32 / 16	44 LQFP	–40 to +105 °C
MCF51JM32VLD	MCF51JM32 ColdFire Microcontroller	32 / 16	44 LQFP	–40 to +105 °C

1.5 Pinouts and Packaging

Figure 2 shows the pinout of the 80-pin LQFP.

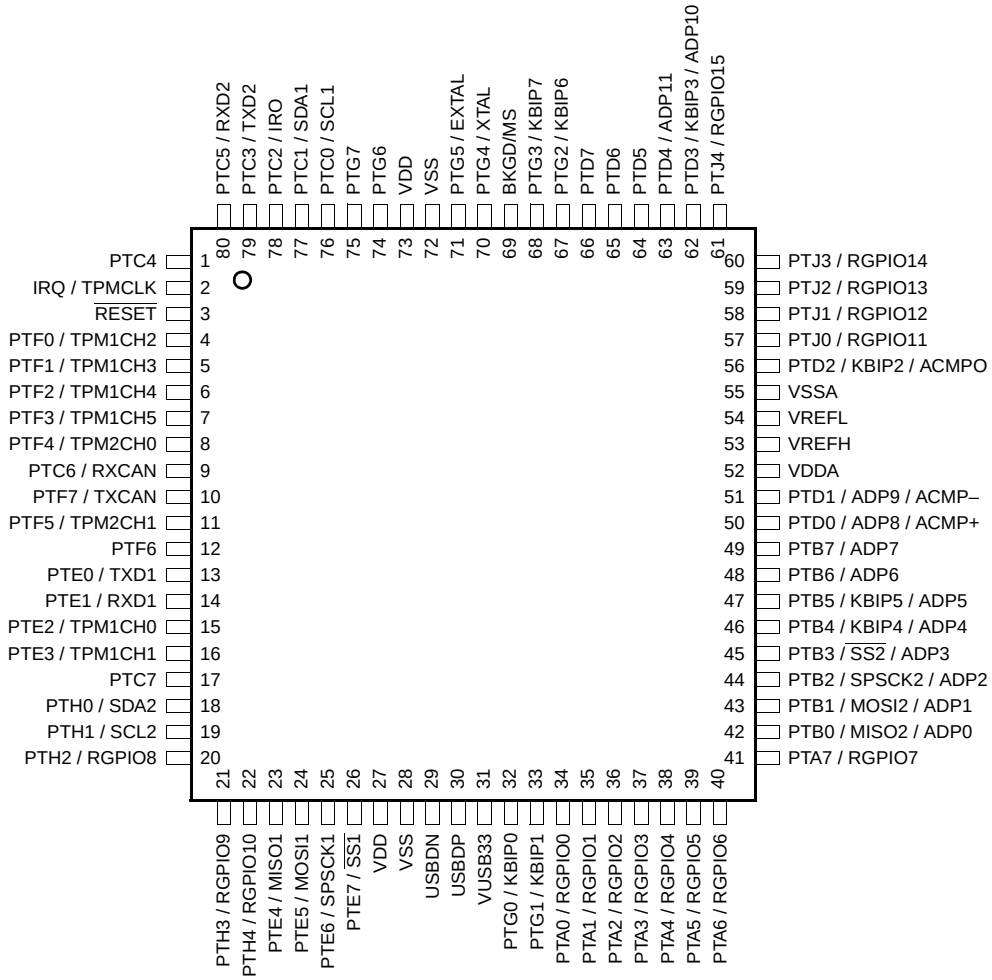


Figure 2. 80-pin LQFP

Figure 3 shows the pinout of the 64-pin LQFP and QFP.

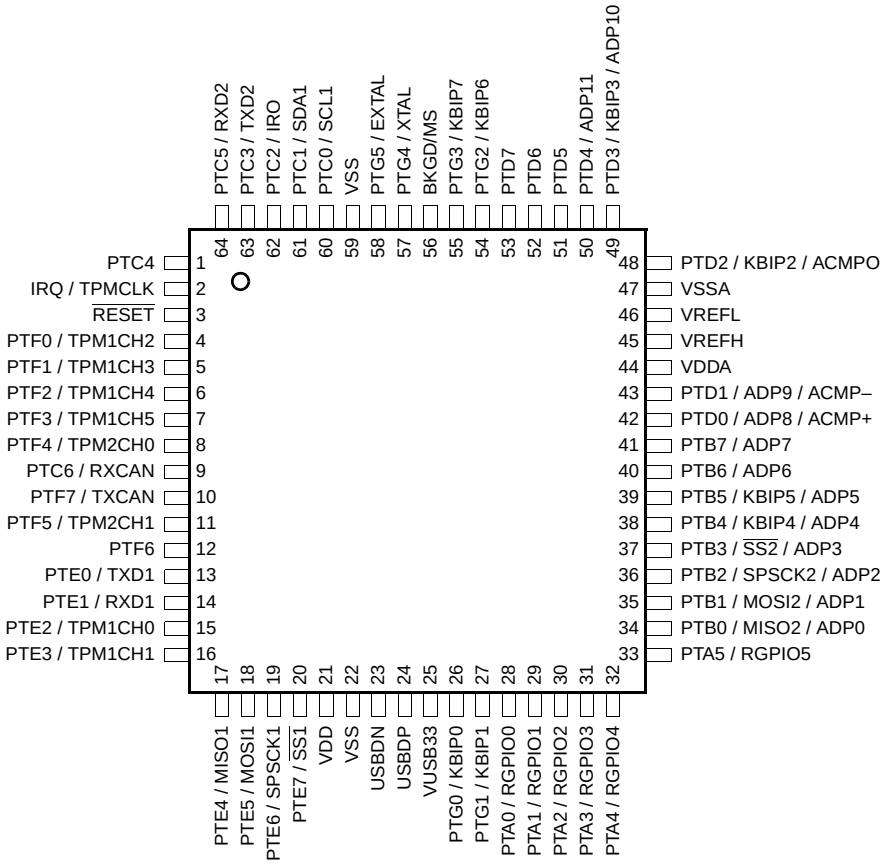


Figure 3. 64-pin QFP and LQFP

Table 4. Pin Assignments by Package and Pin Sharing Priority (continued)

Pin Number			<-- Lowest **Priority** --> Highest		
80	**64**	**44**	**Port Pin**	**Alt 1**	**Alt 2**
16	16	11	PTE3	TPM1CH1	—
17	—	—	PTC7	—	—
18	—	—	PTH0	SDA2	—
19	—	—	PTH1	SCL2	—
20	—	—	PTH2	RGPIO8	—
21	—	—	PTH3	RGPIO9	—
22	—	—	PTH4	RGPIO10	—
23	17	12	PTE4	MISO1	—
24	18	13	PTE5	MOSI1	—
25	19	14	PTE6	SPSCK1	—
26	20	15	PTE7	$\overline{SS1}$	—
27	21	16	—	—	VDD
28	22	17	—	—	VSS
29	23	18	—	—	USBDN
30	24	19	—	—	USBDP
31	25	20	—	—	VUSB33
32	26	21	PTG0	KBIP0	USB_ALT_CLK
33	27	22	PTG1	KBIP1	—
34	28	—	PTA0	RGPIO0	USB_SESSVLD
35	29	—	PTA1	RGPIO1	USB_SESSEND
36	30	—	PTA2	RGPIO2	USB_VBUSVLD
37	31	—	PTA3	RGPIO3	USB_PULLUP(D+)
38	32	—	PTA4	RGPIO4	USB_DM_DOWN
39	33	—	PTA5	RGPIO5	USB_DP_DOWN
40	—	—	PTA6	RGPIO6	USB_ID
41	—	—	PTA7	RGPIO7	—
42	34	23	PTB0	MISO2	ADP0
43	35	24	PTB1	MOSI2	ADP1
44	36	25	PTB2	SPSCK2	ADP2
45	37	26	PTB3	$\overline{SS2}$	ADP3
46	38	27	PTB4	KBIP4	ADP4
47	39	28	PTB5	KBIP5	ADP5
48	40	—	PTB6	ADP6	—

Table 4. Pin Assignments by Package and Pin Sharing Priority (continued)

Pin Number			<-- Lowest **Priority** --> Highest		
80	**64**	**44**	**Port Pin**	**Alt 1**	**Alt 2**
49	41	—	PTB7	ADP7	—
50	42	29	PTD0	ADP8	ACMP+
51	43	30	PTD1	ADP9	ACMP–
52	44	31	—	—	VDDA
53	45		—	—	VREFH
54	46	32	—	—	VREFL
55	47		—	—	VSSA
56	48	33	PTD2	KBIP2	ACMPO
57	—	—	PTJ0	RGPIO11	—
58	—	—	PTJ1	RGPIO12	—
59	—	—	PTJ2	RGPIO13	—
60	—	—	PTJ3	RGPIO14	—
61	—	—	PTJ4	RGPIO15	—
62	49	—	PTD3	KBIP3	ADP10
63	50	—	PTD4	ADP11	—
64	51	—	PTD5	—	—
65	52	—	PTD6	—	—
66	53	—	PTD7	—	—
67	54	34	PTG2	KBIP6	—
68	55	35	PTG3	KBIP7	—
69	56	36	—	BKGD	MS
70	57	37	PTG4	XTAL	
71	58	38	PTG5	EXTAL	
72	59	39	—	—	VSS
73	—	—	—	—	VDD
74	—	—	PTG6	—	—
75	—	—	PTG7	—	—
76	60	40	PTC0	SCL1	—
77	61	41	PTC1	SDA1	—
78	62	42	PTC2	IRO	—
79	63	43	PTC3	TXD2	—
80	64	44	PTC5	RXD2	—

2 Preliminary Electrical Characteristics

This section contains electrical specification tables and reference timing diagrams for the MCF51JM128 microcontroller, including detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications.

The electrical specifications are preliminary and are from previous designs or design simulations. These specifications may not be fully tested or guaranteed at this early stage of the product life cycle. These specifications will, however, be met for production silicon. Finalized specifications will be published after complete characterization and device qualifications have been completed.

NOTE

The parameters specified in this data sheet supersede any values found in the module specifications.

2.1 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

Table 5. Parameter Classifications

P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

NOTE

The classification is shown in the column labeled C in the parameter tables where appropriate.

2.2 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in Table 6 may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this section.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, V_{SS} or V_{DD}).

Table 9. ESD and Latch-Up Protection Characteristics

Num	Rating	Symbol	Min	Max	Unit
1	Human Body Model (HBM)	V_{HBM}	+/– 2000	—	V
2	Charge Device Model (CDM)	V_{CDM}	+/– 500	—	V
3	Latch-up Current at T_A = 105°C	I_{LAT}	+/– 100	—	mA

2.5 DC Characteristics

This section includes information about power supply requirements, I/O pin characteristics, and power supply current in various operating modes.

Table 10. DC Characteristics

Num	C	Parameter	Symbol	Min	Typ[1]	Max	Unit
1		Operating voltage[2]		2.7	—	5.5	V
2	P	Output high voltage — Low Drive (PTxDSn = 0) 5 V, I_{Load} = –4 mA 3 V, I_{Load} = –2 mA 5 V, I_{Load} = –2 mA 3 V, I_{Load} = –1 mA	V_{OH}	 V_{DD} – 1.5 V_{DD} – 1.5 V_{DD} – 0.8 V_{DD} – 0.8	 — — — —	 — — — —	V
		Output high voltage — High Drive (PTxDSn = 1) 5 V, I_{Load} = –15 mA 3 V, I_{Load} = –8 mA 5 V, I_{Load} = –8 mA 3 V, I_{Load} = –4 mA		 V_{DD} – 1.5 V_{DD} – 1.5 V_{DD} – 0.8 V_{DD} – 0.8	 — — — —	 — — — —	
3	P	Output low voltage — Low Drive (PTxDSn = 0) 5 V, I_{Load} = 4mA 3 V, I_{Load} = 2 mA 5 V, I_{Load} = 2 mA 3 V, I_{Load} = 1 mA	V_{OL}		 — — — —	 1.5 1.5 0.8 0.8	V
		Output low voltage — High Drive (PTxDSn = 1) 5 V, I_{Load} = 15 mA 3 V, I_{Load} = 8 mA 5 V, I_{Load} = 8 mA 3 V, I_{Load} = 4 mA			 — — — —	 1.5 1.5 0.8 0.8	
4	P	Output high current — Max total I_{OH} for all ports 5V 3V	I_{OHT}	 — —	 — —	 100 60	mA
5	P	Output low current — Max total I_{OL} for all ports 5V 3V	I_{OLT}	 — —	 — —	 100 60	mA
6	P	Input high voltage; all digital inputs	V_{IH}				V
		V_{DD} = 5V V_{DD} = 3V		3.25 2.10	— —	— —	

Table 10. DC Characteristics (continued)

Num	C	Parameter	Symbol	Min	Typ[1]	Max	Unit
7	P	Input low voltage; all digital inputs V_{DD} = 5V V_{DD} = 3V	V_{IL}	—	—	 1.75 1.05	V
8	P	Input hysteresis; all digital inputs	V_{hys}	0.06 x V_{DD}			mV
9	P	Input leakage current; input only pins[3]	$\|I_{In}\|$	—	0.1	1	µA
10	P	High Impedance (off-state) leakage current[3]	$\|I_{OZ}\|$	—	0.1	1	µA
11	P	Internal pullup resistors[4]	R_{PU}	20	45	65	kΩ
12	P	Internal pulldown resistors[5]	R_{PD}	20	45	65	kΩ
13		Internal pullup resistor to USBDP (to V_{USB33}) Idle Transmit	R_{PUPD}	 900 1425	 1300 2400	 1575 3090	kΩ
14	C	Input Capacitance; all non-supply pins	C_{In}	—	—	8	pF
15	D	RAM retention voltage[6]	V_{RAM}	—	0.6	1.0	V
16	P	POR rearm voltage	V_{POR}	0.9	1.4	2.0	V
17	D	POR rearm time	t_{POR}	10	—	—	µs
18	P	Low-voltage detection threshold — high range V_{DD} falling V_{DD} rising	V_{LVD1}	 3.9 4.0	 4.0 4.1	 4.1 4.2	V
19	P	Low-voltage detection threshold — low range V_{DD} falling V_{DD} rising	V_{LVD0}	 2.48 2.54	 2.56 2.62	 2.64 2.70	V
20	C	Low-voltage warning threshold — high range 1 V_{DD} falling V_{DD} rising	V_{LVW3}	 4.5 4.6	 4.6 4.7	 4.7 4.8	V
21	P	Low-voltage warning threshold — high range 0 V_{DD} falling V_{DD} rising	V_{LVW2}	 4.2 4.3	 4.3 4.4	 4.4 4.5	V
22	P	Low-voltage warning threshold low range 1 V_{DD} falling V_{DD} rising	V_{LVW1}	 2.84 2.90	 2.92 2.98	 3.00 3.06	V
23	C	Low-voltage warning threshold — low range 0 V_{DD} falling V_{DD} rising	V_{LVW0}	 2.66 2.72	 2.74 2.80	 2.82 2.88	V
24	T	Low-voltage inhibit reset/recover hysteresis 5 V 3 V	V_{hys}	 — —	 100 60	 — —	mV

1 Typical values are based on characterization data at 25°C unless otherwise stated.
2 Operating voltage with USB enabled can be found in Section 2.14, “USB Electricals.”
3 Measured with $V_{In} = V_{DD}$ or V_{SS}.
4 Measured with $V_{In} = V_{SS}$.
5 Measured with $V_{In} = V_{DD}$.
6 This is the voltage below which the contents of RAM are not guaranteed to be maintained.

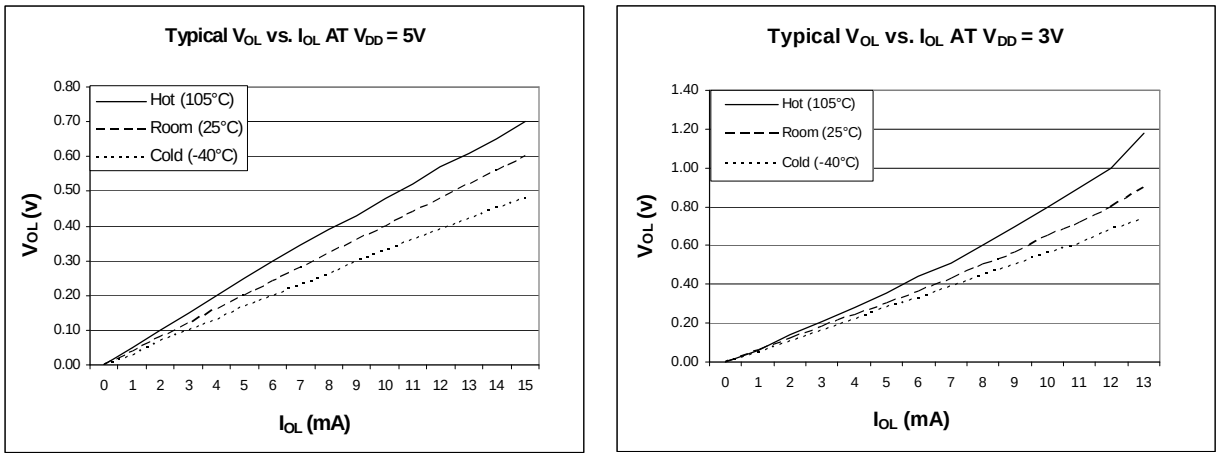


Figure 5. Typical Low-side Drive (sink) characteristics – High Drive (PTxDSn = 1)

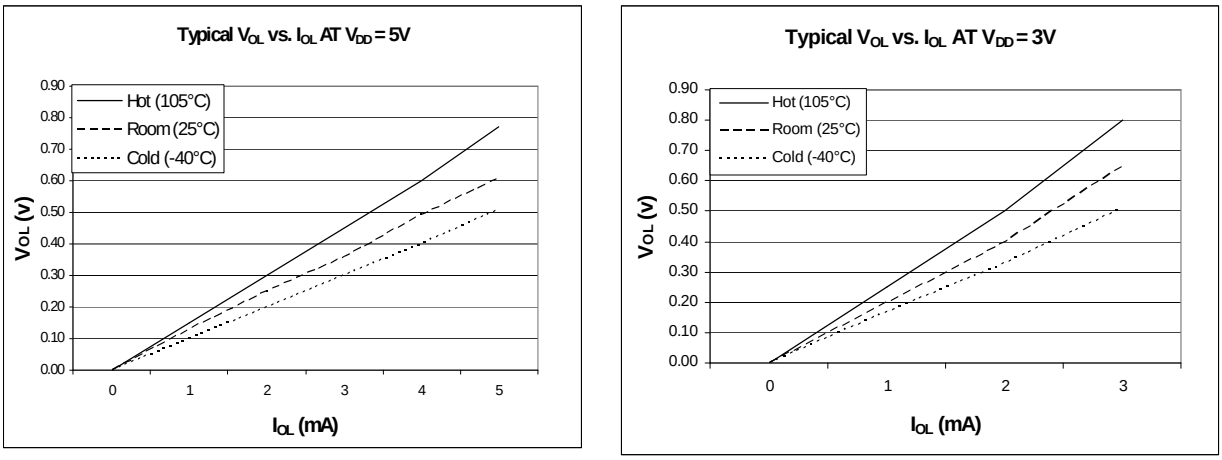


Figure 6. Typical Low-side Drive (sink) characteristics – Low Drive (PTxDSn = 0)

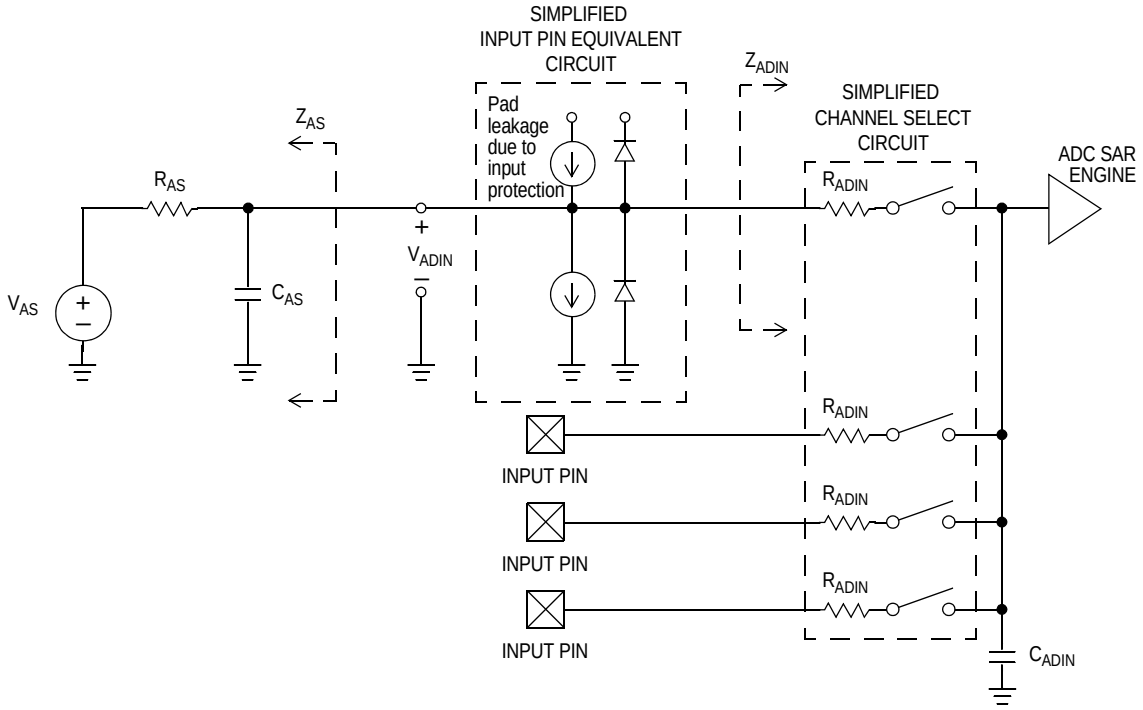


Figure 9. ADC Input Impedance Equivalency Diagram

Table 14. 5 Volt 12-bit ADC Characteristics (V_{REFH} = V_{DDA}, V_{REFL} = V_{SSA})

Characteristic	Conditions	C	Symb	Min	Typ[1]	Max	Unit	Comment
Supply Current ADLPC=1 ADLSMP=1 ADCO=1		T	I_{DDAD}	—	133	—	µA	
Supply Current ADLPC=1 ADLSMP=0 ADCO=1		T	I_{DDAD}	—	218	—	µA	
Supply Current ADLPC=0 ADLSMP=1 ADCO=1		T	I_{DDAD}	—	327	—	µA	
Supply Current ADLPC=0 ADLSMP=0 ADCO=1		P	I_{DDAD}	—	0.582	1	mA	
Supply Current	Stop, Reset, Module Off		I_{DDAD}	—	0.011	1	µA	
ADC Asynchronous Clock Source	High Speed (ADLPC=0)	T	f_{ADACK}	2	3.3	5	MHz	t_{ADACK} = $1/f_{ADACK}$
	Low Power (ADLPC=1)			1.25	2	3.3		

Table 14. 5 Volt 12-bit ADC Characteristics (V_{REFH} = V_{DDA}, V_{REFL} = V_{SSA}) (continued)

Characteristic	Conditions	C	Symb	Min	Typ[1]	Max	Unit	Comment
Conversion Time (Including sample time)	Short Sample (ADLSMP=0)	T	t_{ADC}	—	20	—	ADCK cycles	See Table 9 for conversion time variances
	Long Sample (ADLSMP=1)			—	40	—		
Sample Time	Short Sample (ADLSMP=0)	T	t_{ADS}	—	3.5	—	ADCK cycles	
	Long Sample (ADLSMP=1)			—	23.5	—		
Total Unadjusted Error	12 bit mode	T	E_{TUE}	—	±3.0	—	LSB[2]	Includes quantization
	10 bit mode	P		—	±1	±2.5		
	8 bit mode	T		—	±0.5	±1.0		
Differential Non-Linearity	12 bit mode	T	DNL	—	±1.75	—	LSB[2]	
	10 bit mode[3]	P		—	±0.5	±1.0		
	8 bit mode[3]	T		—	±0.3	±0.5		
Integral Non-Linearity	12 bit mode	T	INL	—	±1.5	—	LSB[2]	
	10 bit mode	T		—	±0.5	±1.0		
	8 bit mode	T		—	±0.3	±0.5		
Zero-Scale Error	12 bit mode	T	E_{ZS}	—	±1.5	—	LSB[2]	V_{ADIN} = V_{SSAD}
	10 bit mode	P		—	±0.5	±1.5		
	8 bit mode	T		—	±0.5	±0.5		
Full-Scale Error	12 bit mode	T	E_{FS}	—	±1	—	LSB[2]	V_{ADIN} = V_{DDAD}
	10 bit mode	T		—	±0.5	±1		
	8 bit mode	T		—	±0.5	±0.5		
Quantization Error	12 bit mode	D	E_Q	—	-1 to 0	—	LSB[2]	
	10 bit mode			—	—	±0.5		
	8 bit mode			—	—	±0.5		
Input Leakage Error	12 bit mode	D	E_{IL}	—	±1	—	LSB[2]	Pad leakage[4] * R_{AS}
	10 bit mode			—	±0.2	±2.5		
	8 bit mode			—	±0.1	±1		
Temp Sensor Voltage	25°C	D	V_{TEMP25}	—	1.396	—	V	
Temp Sensor Slope	-40°C - 25°C	D	m	—	3.266	—	mV/°C	
	25°C - 125°C			—	3.638	—		

1 Typical values assume V_{DDA} = 5.0V, Temp = 25°C, f_{ADCK}=1.0MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

2 1 LSB = $(V_{REFH} - V_{REFL})/2^N$

3 Monotonicity and No-Missing-Codes guaranteed in 10 bit and 8 bit modes

4 Based on input pad leakage current. Refer to pad electricals.

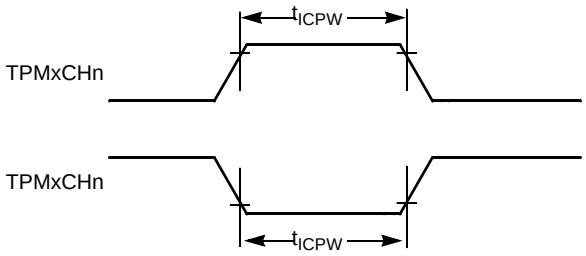


Figure 13. Timer Input Capture Pulse

2.11.3 MSCAN

Table 19. MSCAN Wake-up Pulse Characteristics

Num	C	Parameter	Symbol	Min	Typ[1]	Max	Unit
1	D	MSCAN Wake-up dominant pulse filtered	t_{WUP}			2	µs
2	D	MSCAN Wake-up dominant pulse pass	t_{WUP}	5		5	µs

1 Typical values are based on characterization data at V_{DD} = 5.0V, 25°C unless otherwise stated.

2.13 Flash Specifications

This section provides details about program/erase times and program-erase endurance for the Flash memory.

Program and erase operations do not require any special power sources other than the normal V_{DD} supply.

Table 21. Flash Characteristics

Num	C	Characteristic	Symbol	Min	Typ[1]	Max	Unit
1		Supply voltage for program/erase	$V_{prog/erase}$	2.7		5.5	V
2		Supply voltage for read operation	V_{Read}	2.7		5.5	V
3		Internal FCLK frequency[2]	f_{FCLK}	150		200	kHz
4		Internal FCLK period (1/FCLK)	t_{Fcyc}	5		6.67	µs
5		Byte program time (random location)(2)	t_{prog}	9			t_{Fcyc}
6		Byte program time (burst mode)(2)	t_{Burst}	4			t_{Fcyc}
7		Page erase time[3]	t_{Page}	4000			t_{Fcyc}
8		Mass erase time(2)	t_{Mass}	20,000			t_{Fcyc}
9	C	Program/erase endurance[4] T_L to T_H = –40°C to + 105°C T = 25°C		10,000 —	— 100,000	— —	cycles
10		Data retention[5]	t_{D_ret}	15	100	—	years

1 Typical values are based on characterization data at V_{DD} = 5.0 V, 25°C unless otherwise stated.

2 The frequency of this clock is controlled by a software setting.

3 These values are hardware state machine controlled. User code does not need to count cycles. This information supplied for calculating approximate time to program and erase.

4 Typical endurance for Flash was evaluated for this product family on the 9S12Dx64. For additional information on how Freescale Semiconductor defines typical endurance, please refer to Engineering Bulletin EB619/D, *Typical Endurance for Nonvolatile Memory*.

5 Typical data retention values are based on intrinsic capability of the technology measured at high temperature and de-rated to 25°C using the Arrhenius equation. For additional information on how Freescale Semiconductor defines typical data retention, please refer to Engineering Bulletin EB618/D, Typical Data Retention for Nonvolatile Memory.

2.14 USB Electricals

The USB electricals for the USBOTG module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit http://www.usb.org.

If the Freescale USBOTG implementation requires additional or deviant electrical characteristics, this space would be used to communicate that information.

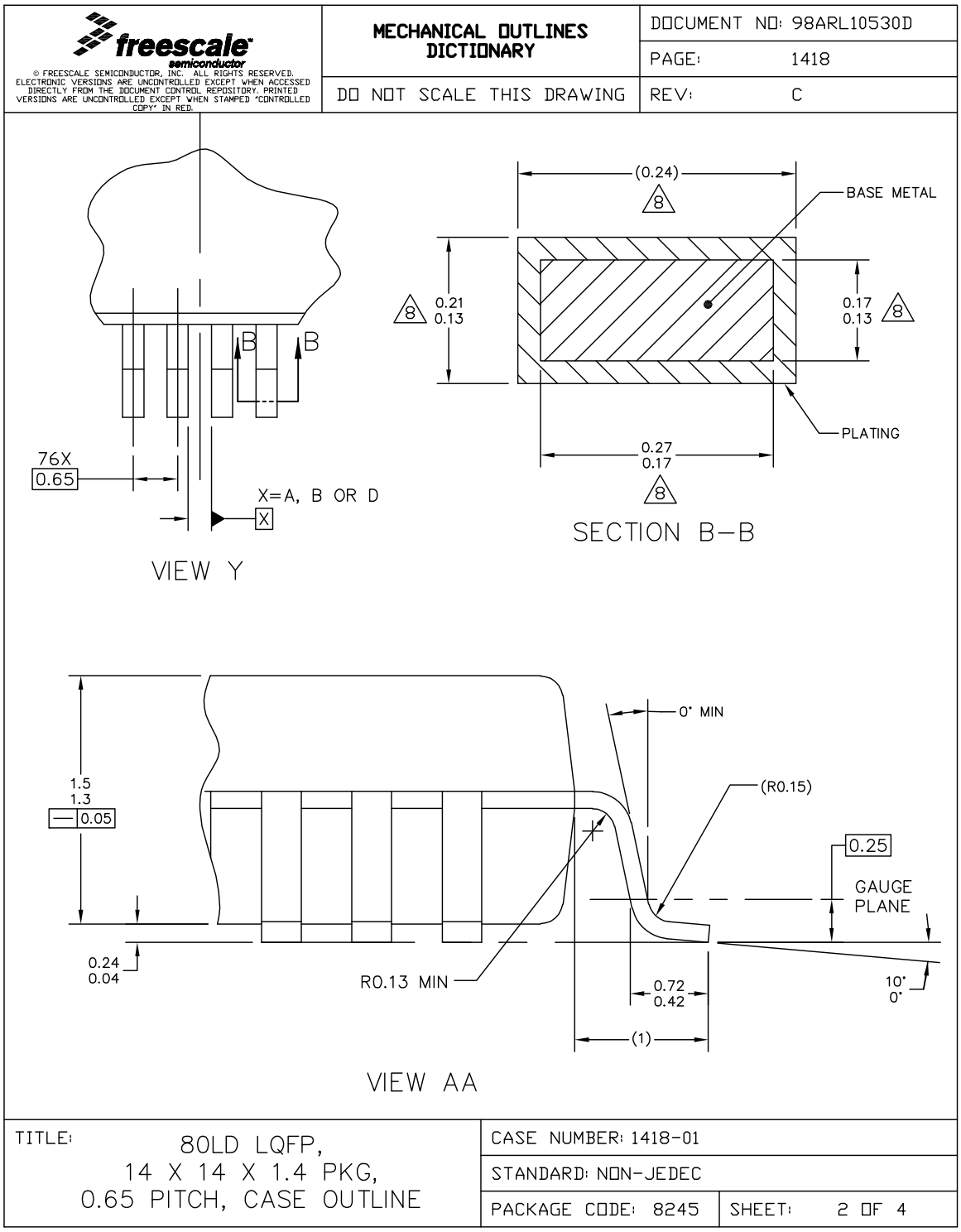
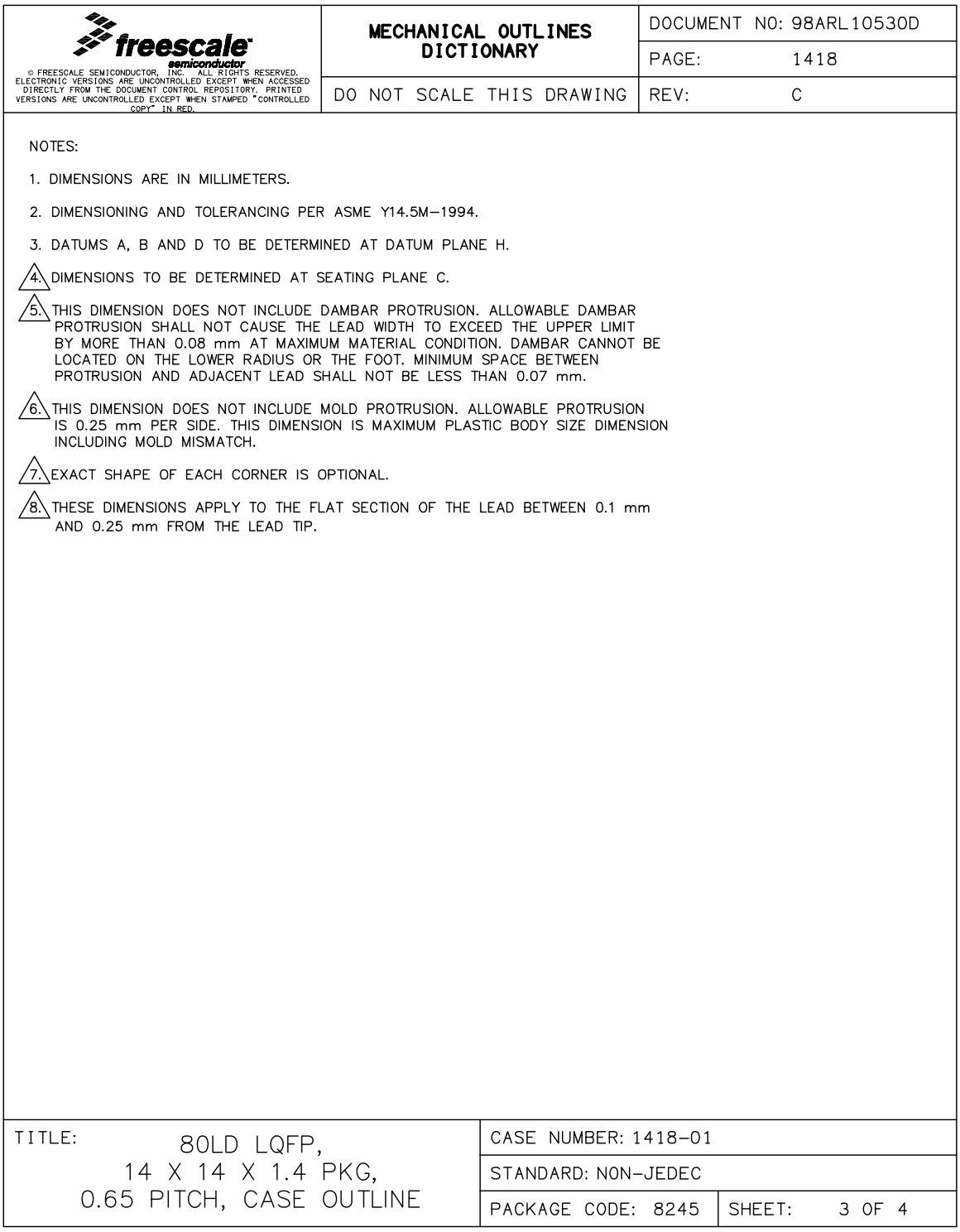


Figure 19. 80-pin LQFP Diagram - II



freescale semiconductor

MECHANICAL OUTLINES DICTIONARY

DOCUMENT NO: 98ARL10530D

PAGE: 1418

DO NOT SCALE THIS DRAWING

REV: C

NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.
5. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.
6. THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.
7. EXACT SHAPE OF EACH CORNER IS OPTIONAL.
8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 mm AND 0.25 mm FROM THE LEAD TIP.

TITLE: 80LD LQFP, 14 X 14 X 1.4 PKG, 0.65 PITCH, CASE OUTLINE

CASE NUMBER: 1418–01

STANDARD: NON–JEDEC

PACKAGE CODE: 8245

SHEET: 3 OF 4

Figure 20. 80-pin LQFP Diagram - III

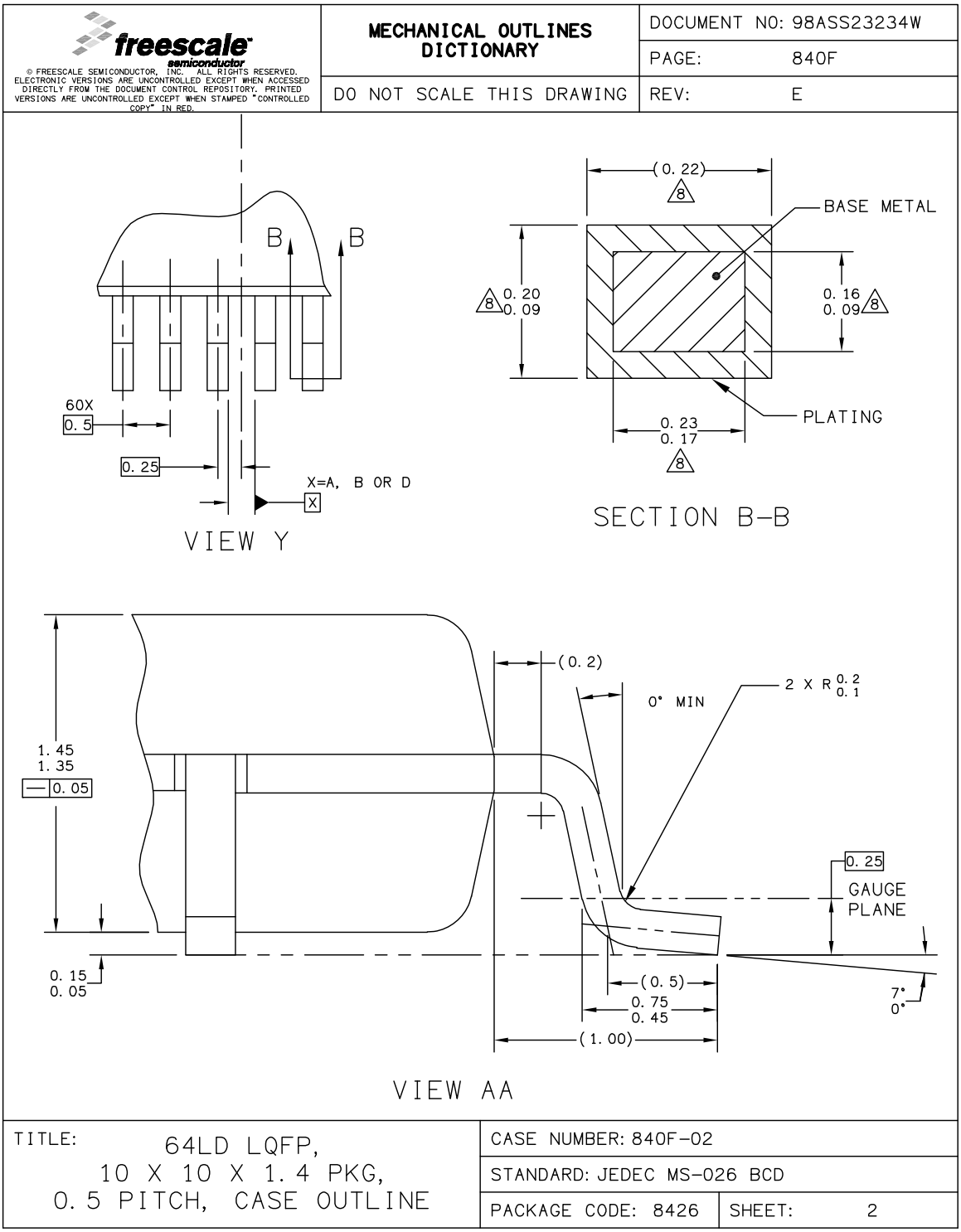


Figure 22. 64-pin LQFP Diagram - II

3.4 44-pin LQFP

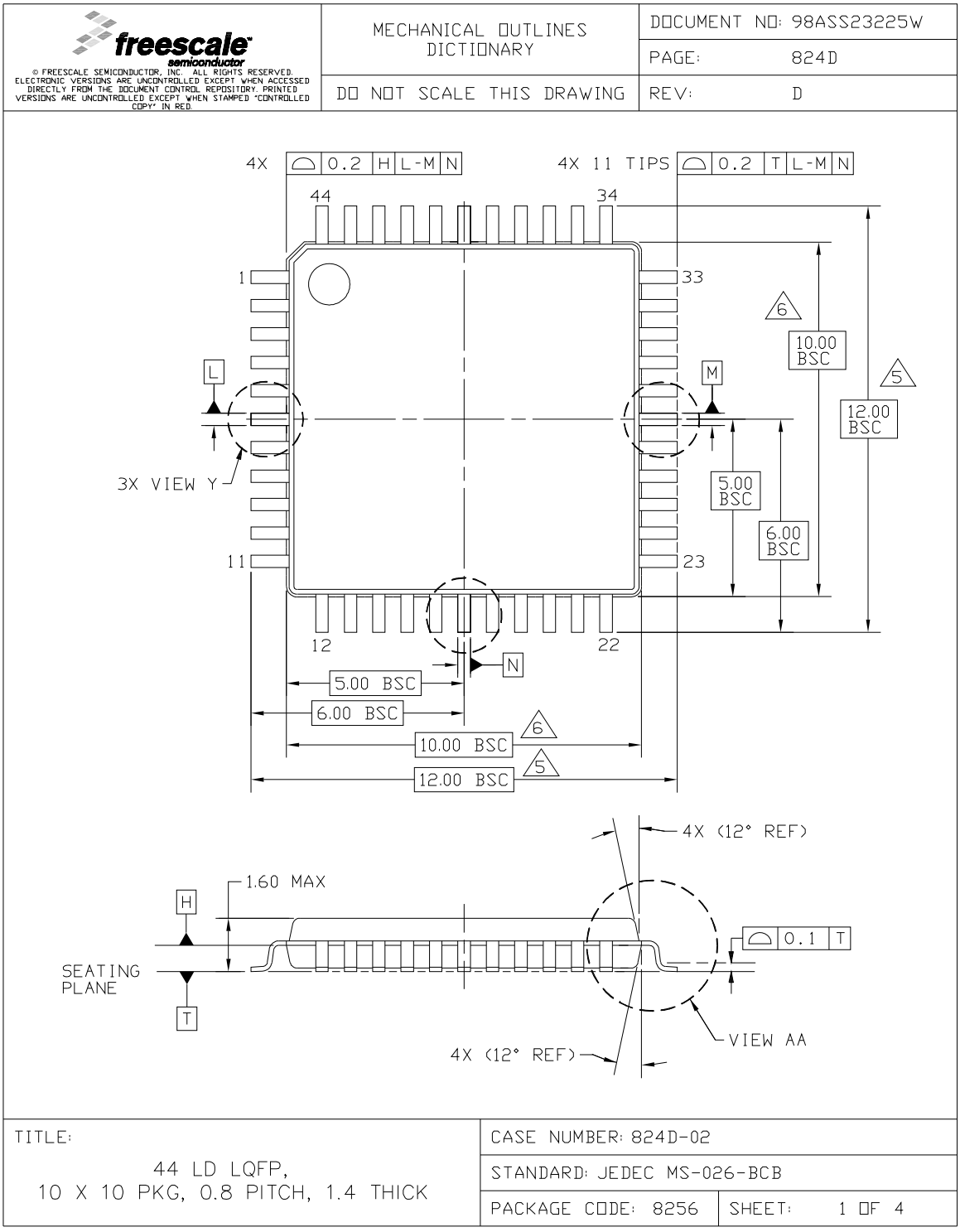


Figure 27. 44-pin LQFP Diagram - I